	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
1	BRS	L1	0	ion adj implation adj system	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 08:56	
2	BRS	L2	821	ion adj implantation adj system	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 08:56	
3	BRS	L5	0	(field adj clamp) near8 (fringing adj field)	USPA T; US-P GPUB; ; EPO; JPO; DERW ENT	2004/01/0 7 08:59	
4	BRS	L4	1	2 and 3	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 08:59	
5	BRS	L3	3	(ion adj source) near4 (ribbon adj ion adj beam)	USPA T; US-P GPUB; EPO; DPO; DERW ENT	2004/01/0 7 09:01	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment
6	BRS	L6	4868	250/396ML,398,396R,49	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 09:04	
7	BRS	L7	176	2 AND 6	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 09:04	
8	BRS	L8	0	3 AND 7	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/01/0 7 09:04	